

EMP312

UPDATED 04/04/2008

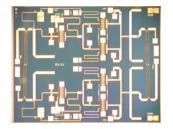
21.0 - 24.0 GHz Power Amplifier MMIC

FEATURES

- 21.0 24.0 GHz Operating Frequency Range
- 28.5dBm Output Power at 1dB Compression
- 13.0 dB Typical Small Signal Gain
- -40dBc OIMD3 @Each Tone Pout 18.5dBm

APPLICATIONS

- Point-to-point and point-to-multipoint radio
- Military Radar Systems



Dimension: 2140um X 2650um Thickness: 75um ± 13um



Caution! ESD sensitive device.

ELECTRICAL CHARACTERISTICS (T_a = 25 °C, 50 ohm, VDD=7V, IDQ=760mA)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	21.0		24.0	GHz
P1dB	Output Power at 1dB Gain Compression	27.0	28.5		dBm
Gss	Small Signal Gain	10.0	13.0		dB
OIMD3	Output 3 rd Order Intermodulation Distortion @∆f=10MHz, Each Tone Pout 18.5dBm		-40	-37	dBc
Input RL	Input Return Loss		-15	-10	dB
Output RL	Output Return Loss		-15	-10	dB
ldss	Saturate Drain Current V _{DS} =3V, V _{GS} =0V	858	1072	1288	mA
V_{DD}	Power Supply Voltage	7		8	V
Rth	Thermal Resistance (Au-Sn Eutectic Attach)		8		°C/W
Tb	Operating Base Plate Temperature	-35		+85	°C

ABSOLUTE MAXIMUM RATINGS FOR CONTINUOUS OPERATION^{1,2}

SYMBOL	CHARACTERISTIC	VALUE		
V_{DS}	Drain to Source Voltage	8 V		
V_{GS}	Gate to Source Voltage	-4 V		
I _{DD}	Drain Current	Idss		
I_{GSF}	Forward Gate Current	15mA		
P_{IN}	Input Power	@ 3dB compression		
T _{CH}	Channel Temperature	150°C		
T_{STG}	Storage Temperature	-65/150°C		
P_T	Total Power Dissipation	12.6W		

^{1.} Operating the device beyond any of the above rating may result in permanent damage.

^{2.} Bias conditions must also satisfy the following equation $V_{DS}^*I_{DS} < (T_{CH} - T_{HS})/R_{TH}$; where T_{HS} = ambient temperature

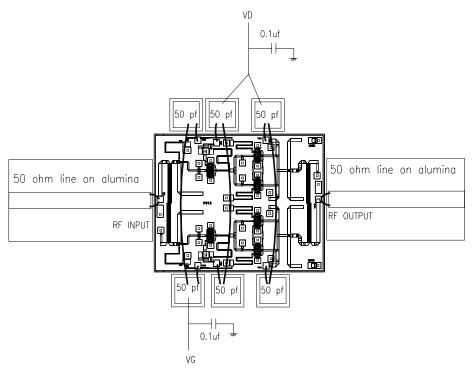


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ASSEMBLY DRAWING



The length of RF wires should be as short as possible. Use at least two wires between RF pad and 50 ohm line and separate the wires to minimize the mutual inductance.

CHIP OUTLINE

